

# CMPA0760020F

0.7 – 6.0 GHz, 25 W GaN MMIC HPA

## Description

The CMPA0760020F is a 25W package MMIC HPA utilizing the high performance, 0.15um GaN on SiC production process. The CMPA0760020F operates from 0.7-6 GHz and supports military communications and electronic warfare along with ISM and EMC amplification. The CMPA0760020F achieves 25 W of saturated output power with 21 dB of large signal gain and typically 36% power-added efficiency under CW operation.

Packaged in a bolt-down, flange package, the CMPA0760020F provides superior performance in a thermally-enhanced package allowing customers to improve SWaP-C benchmarks in their next-generation systems.



Figure 1. CMPA0760020F

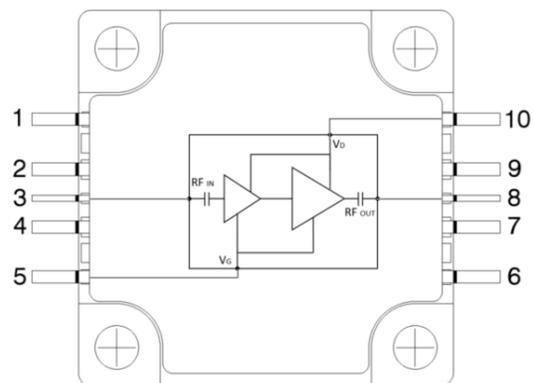


Figure 2. Functional Block Diagram

## Features

- Psat: 25 W
- PAE: 36 %
- LSG: 21 dB
- S21: 33 dB
- S11: -12 dB
- S22: -10 dB
- CW operation

## Applications

- Electronic Warfare
- Military Communications
- ISM Amplifiers
- EMC Amplifiers

Note: Features are typical performance across frequency under 25C operation. Please reference performance charts for additional information.



### Absolute Maximum Ratings

Parameter	Symbol	Units	Value	Conditions
Drain to Source Voltage	$V_{DSS}$	V	84	
Drain Voltage	$V_D$	V	31	
Gate Voltage	$V_G$	V	-1	
Drain Current	$I_D$	A	3	
Gate Current	$I_G$	mA	20	
Input Power	$P_{in}$	dBm	30	
Dissipated Power	$P_{diss}$	W	50	85°C
Storage Temperature	$T_{stg}$	°C	-55, +150	
Mounting Temperature	$T_J$	°C	260	30 seconds
Junction Temperature	$T_J$	°C	225	MTTF > 1E6
Output Mismatch Stress	VSWR	Ψ	5:1	

### Recommended Operating Conditions

Parameter	Symbol	Units	Typical Value	Conditions
Drain Voltage	$V_d$	V	28	
Gate Voltage	$V_g$	V	-1.85	
Drain Current	$I_{dq}$	mA	600	
Input Power	$P_{in}$	dBm	23	
Case Temperature	$T_{case}$	°C	-40 to 85	

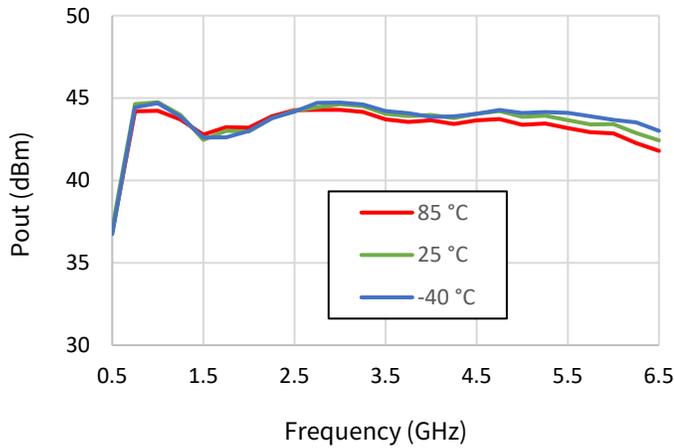
### RF Specifications

Test conditions unless otherwise noted:  $V_d=28$  V,  $I_{dq}=600$ mA, CW,  $P_{in} = 23$  dBm,  $T_{base}=25$ °C, Frequency: 3GHz

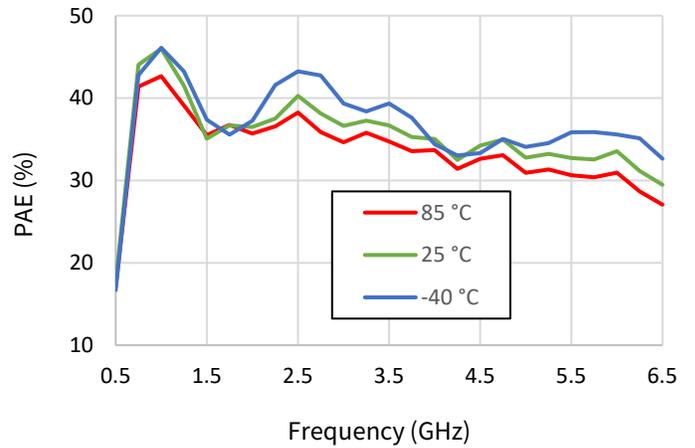
Parameter	Units	Frequency	Min	Typical	Max	Conditions
Frequency	GHz		0.7		6.0	
Output Power	dBm	0.7		44		
		3		44		
		6		43		
Power-added Efficiency	%	0.7		40		
		3		36		
		6		33		
LSG	dB	0.7		21		
		3		21		
		6		20		
Small-Signal Gain	dB	0.7		30		Pin = -20 dBm
		3		33		
		6		35		
Input Return Loss	dB			12		Pin = -20 dBm
Output Return Loss	dB			10		Pin = -20 dBm

Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=600\text{ mA}$ , CW,  $P_{in} = 23\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

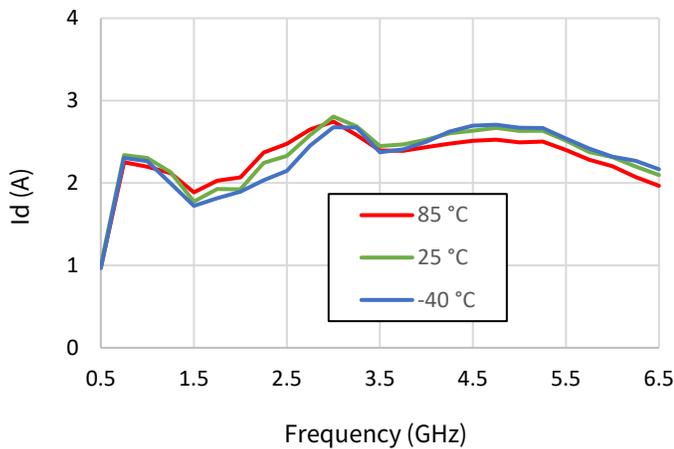
**Figure 3: Pout v. Frequency v. Temperature**



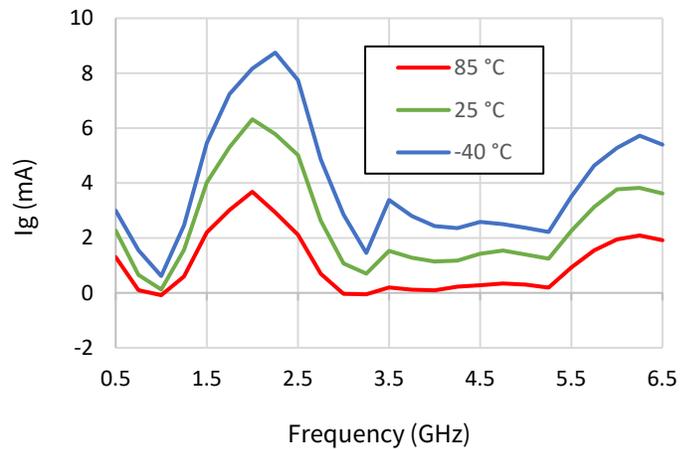
**Figure 4: PAE v. Frequency v. Temperature**



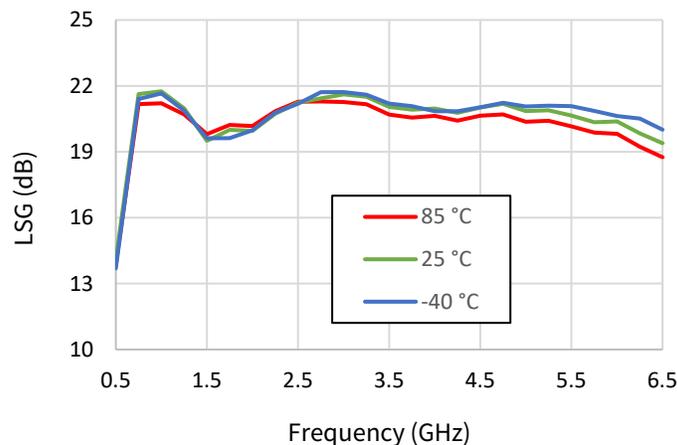
**Figure 5: Id v. Frequency v. Temperature**



**Figure 6: Ig v. Frequency v. Temperature**

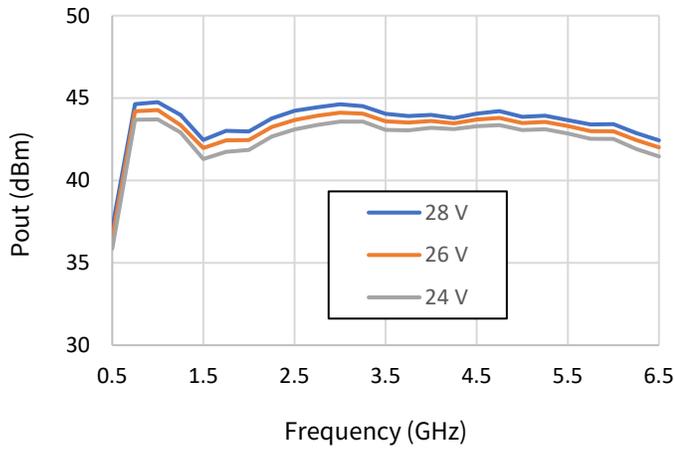


**Figure 7: LSG v. Frequency v. Temperature**

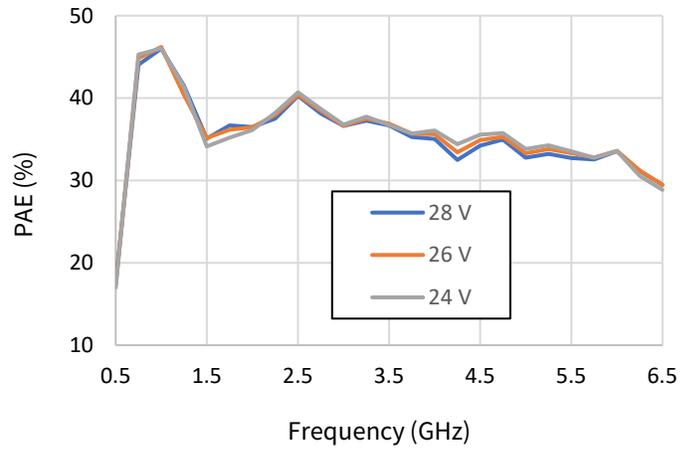


Test conditions unless otherwise noted: Vd=28 V, Idq=600mA, CW, Pin = 23 dBm, T<sub>base</sub>=25 °C, Frequency: 3GHz

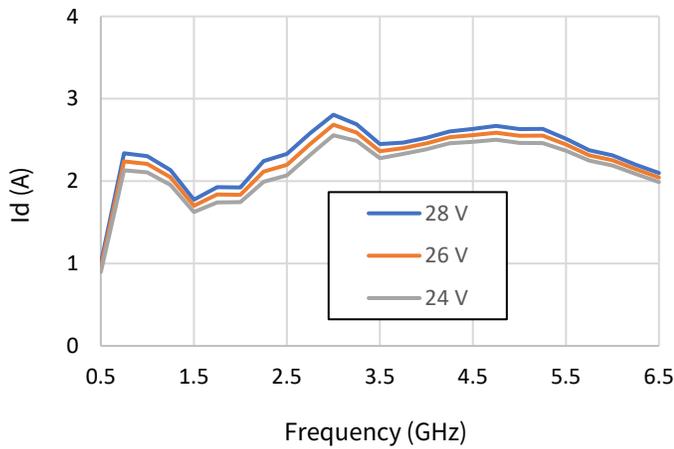
**Figure 8: Pout v. Frequency v. Vd**



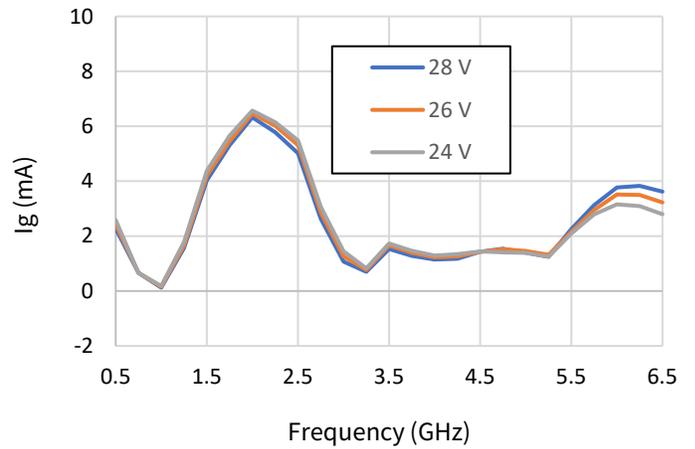
**Figure 9: PAE v. Frequency v. Vd**



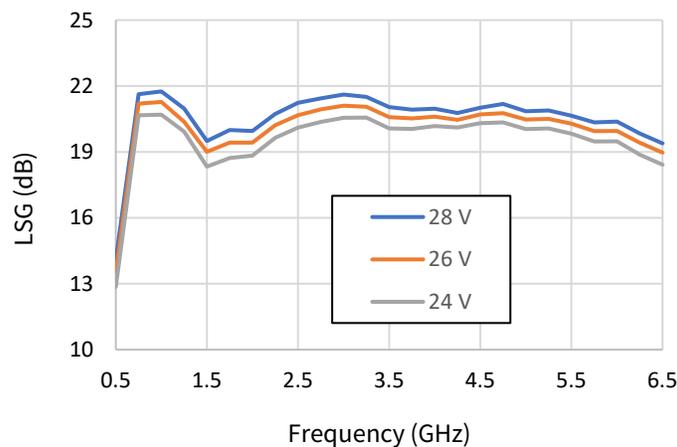
**Figure 10: Id v. Frequency v. Vd**



**Figure 11: Ig v. Frequency v. Vd**

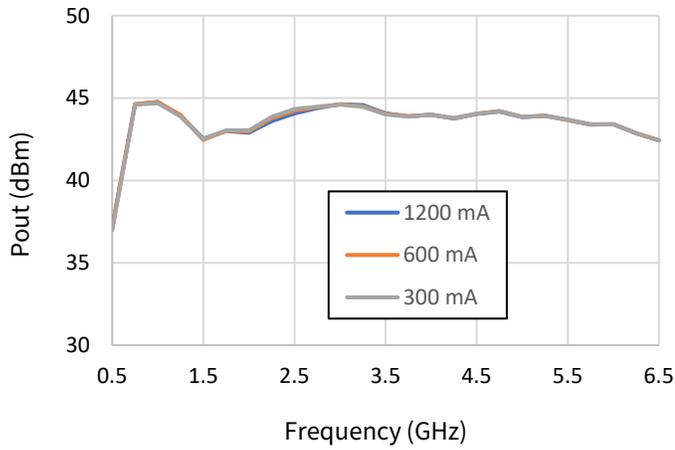


**Figure 12: LSG v. Frequency v. Vd**

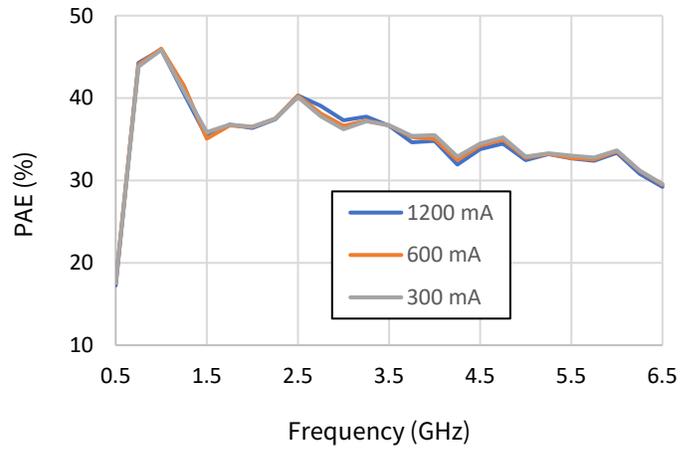


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=600\text{ mA}$ , CW,  $P_{in} = 23\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

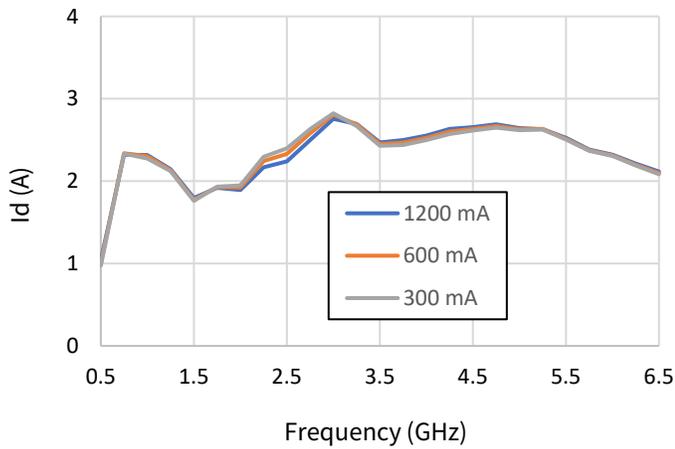
**Figure 13: Pout v. Frequency v. Idq**



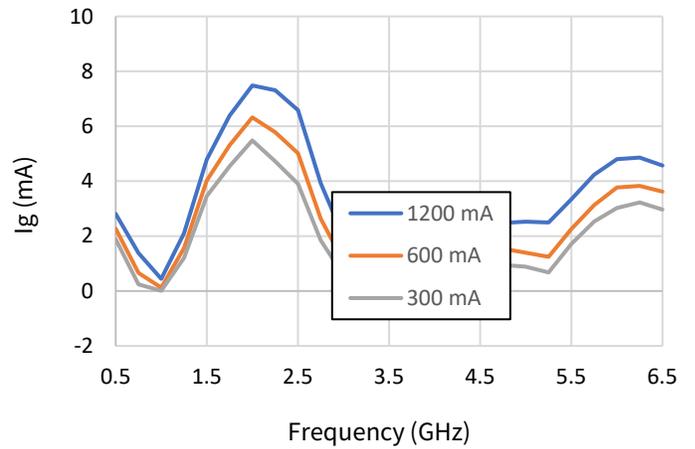
**Figure 14: PAE v. Frequency v. Idq**



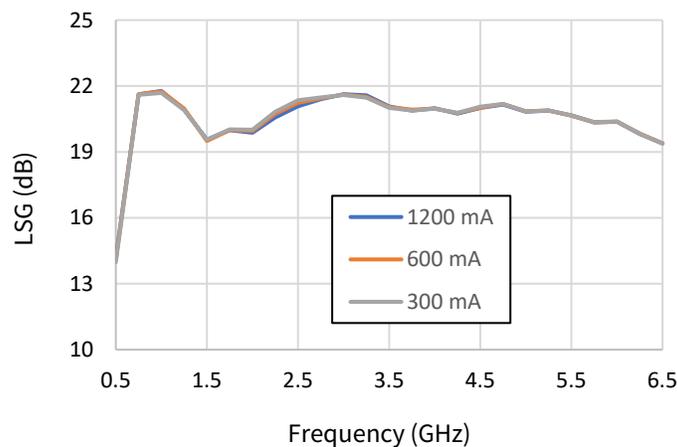
**Figure 15: Id v. Frequency v. Idq**



**Figure 16: Ig v. Frequency v. Idq**

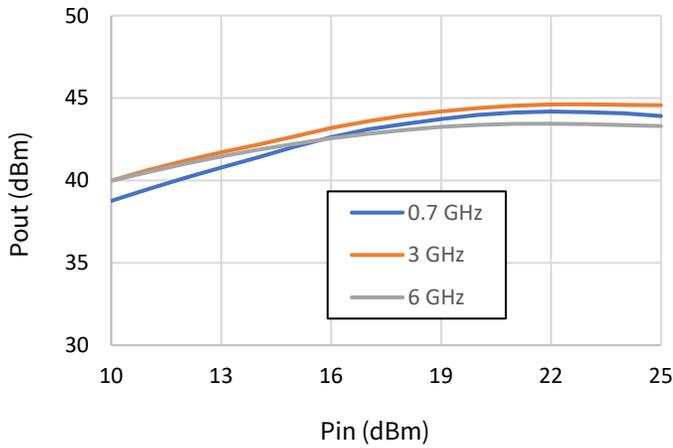


**Figure 17: LSG v. Frequency v. Idq**

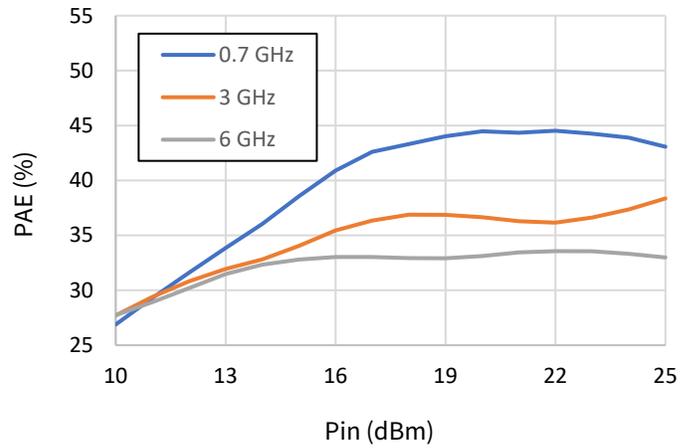


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=600\text{ mA}$ , CW,  $P_{in} = 23\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

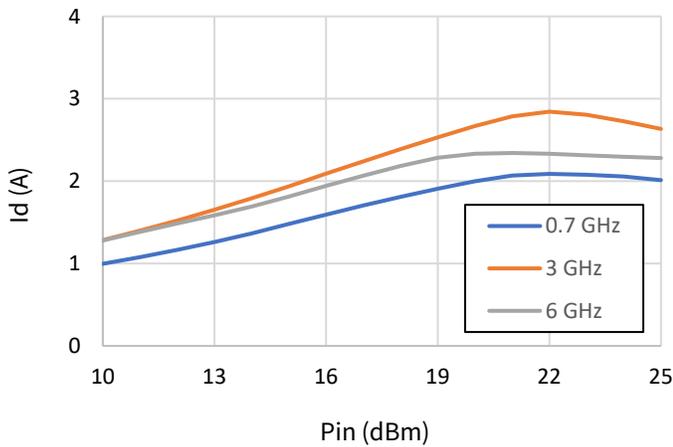
**Figure 18: Pout v. Pin v. Frequency**



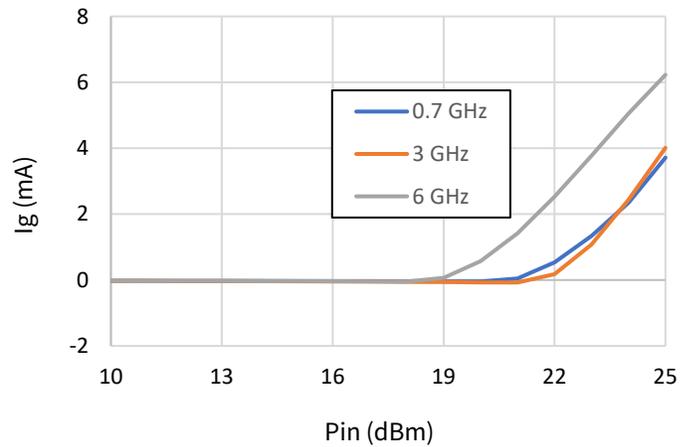
**Figure 19: PAE v. Pin v. Frequency**



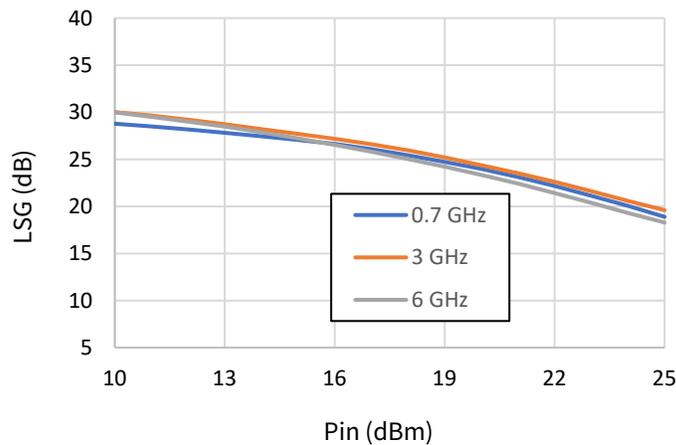
**Figure 20: Id v. Pin v. Frequency**



**Figure 21: Ig v. Pin v. Frequency**

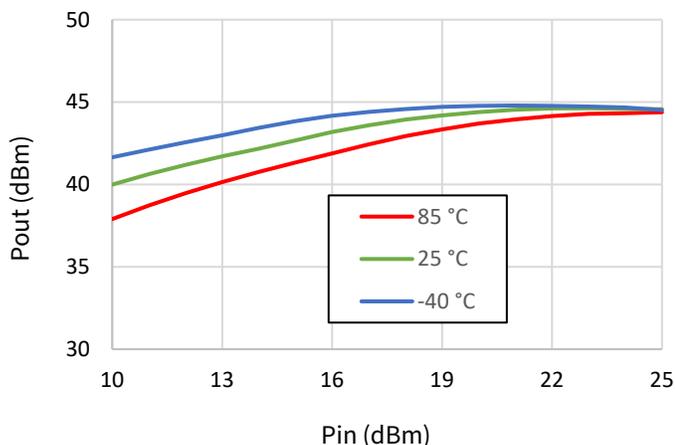


**Figure 22: Gain v. Pin v. Frequency**

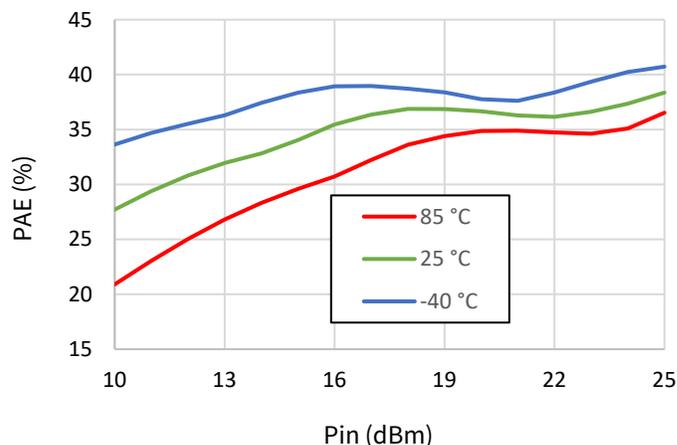


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=600\text{ mA}$ , CW,  $P_{in} = 23\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

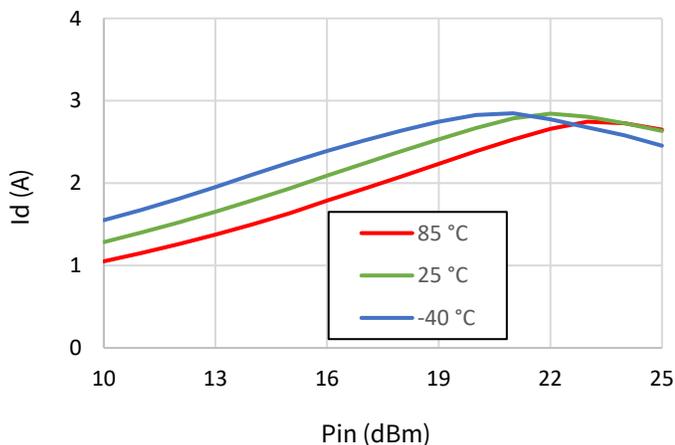
**Figure 23: Pout v. Pin v. Temperature**



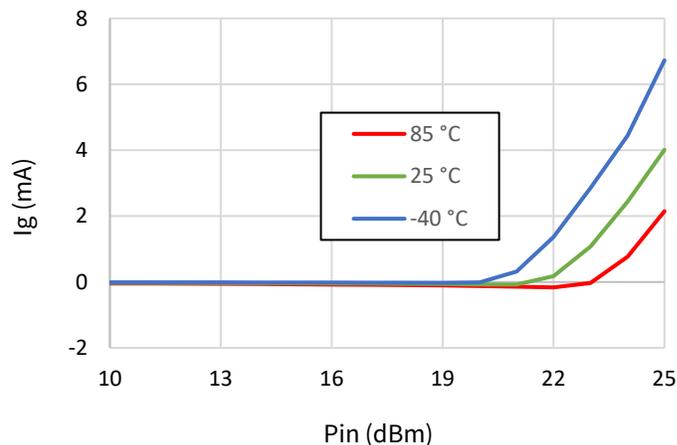
**Figure 24: PAE v. Pin v. Temperature**



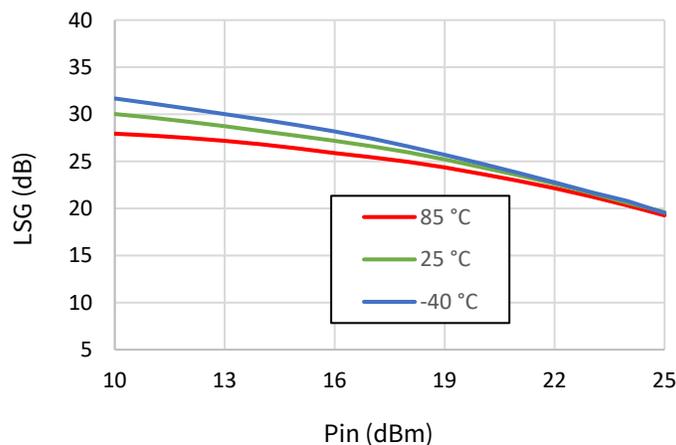
**Figure 25: Id v. Pin v. Temperature**



**Figure 26: Ig v. Pin v. Temperature**

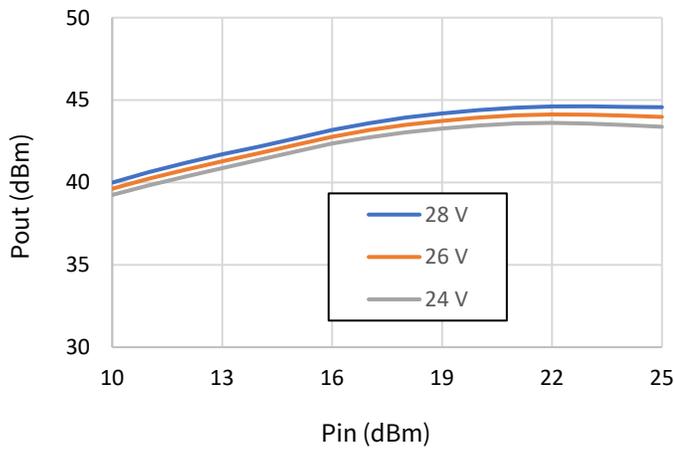


**Figure 27: Gain v. Pin v. Temperature**

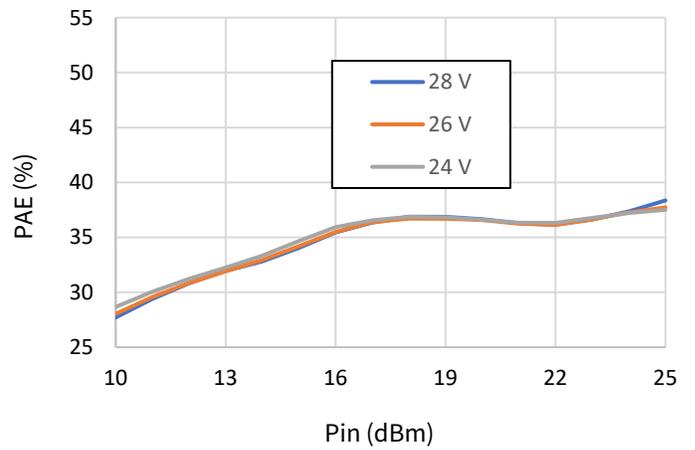


Test conditions unless otherwise noted: Vd=28 V, Idq=600mA, CW, Pin = 23 dBm, T<sub>base</sub>=25 °C, Frequency: 3GHz

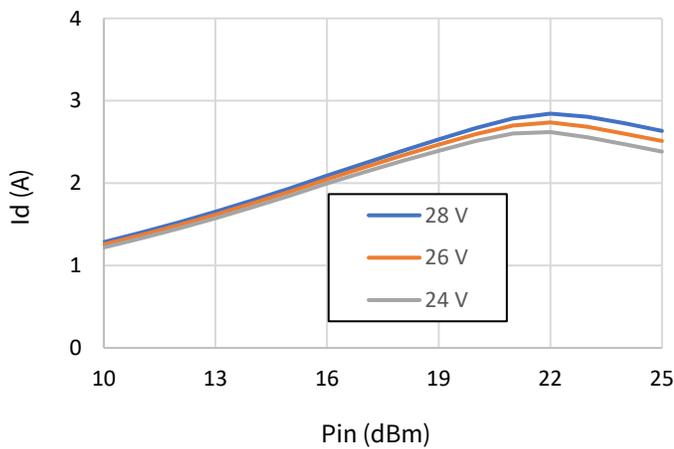
**Figure 28: Pout v. Pin v. Vd**



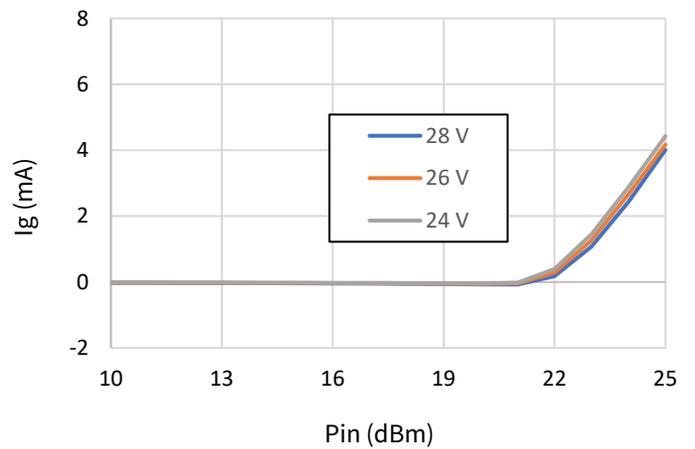
**Figure 29: PAE v. Pin v. Vd**



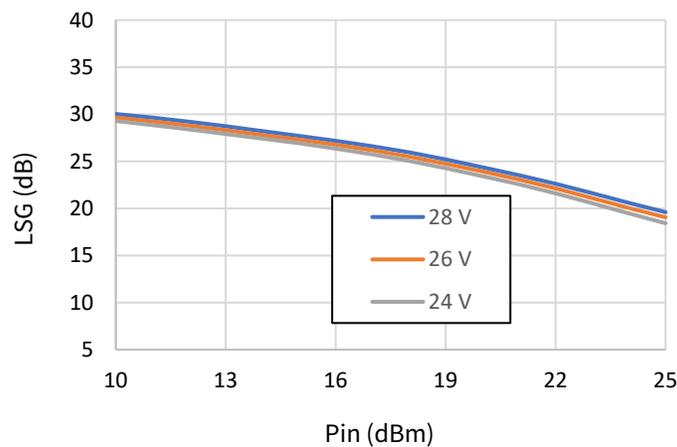
**Figure 30: Id v. Pin v. Vd**



**Figure 31: Ig v. Pin v. Vd**

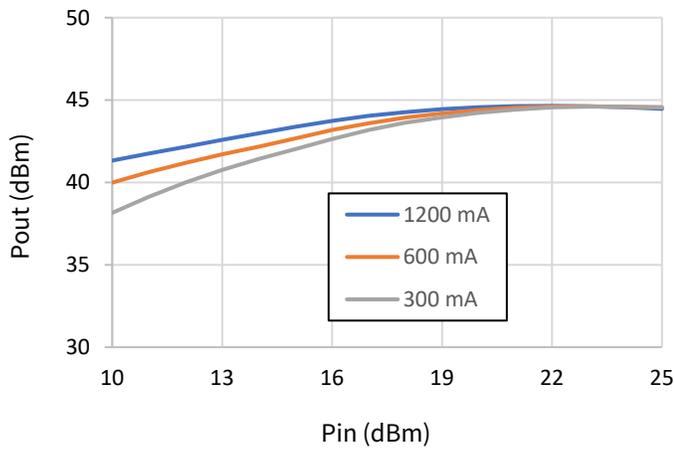


**Figure 32: Gain v. Pin v. Vd**

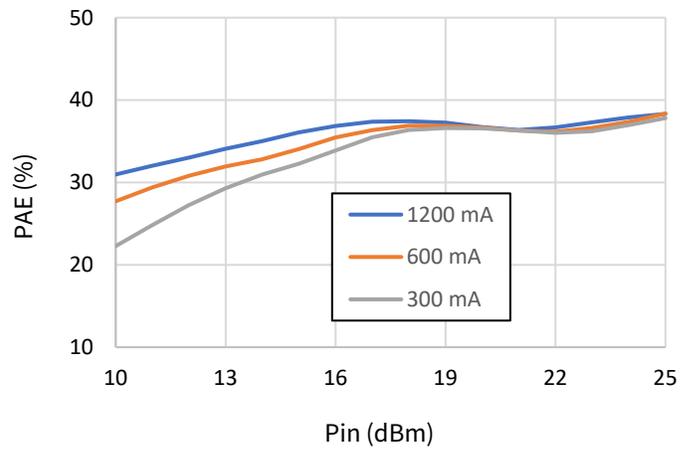


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=600\text{ mA}$ , CW,  $P_{in} = 23\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

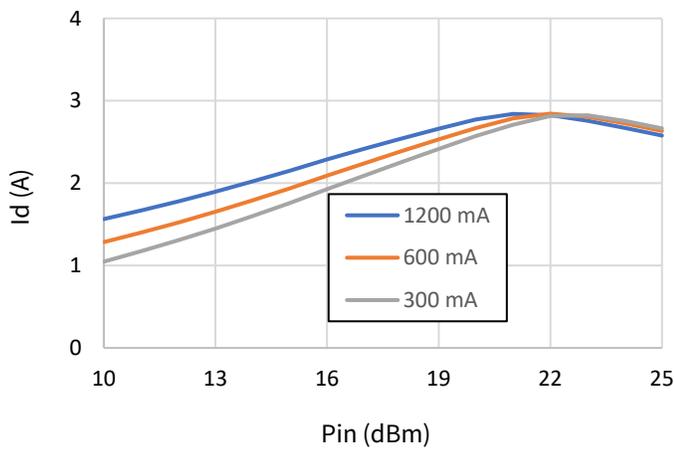
**Figure 33: Pout v. Pin v. Idq**



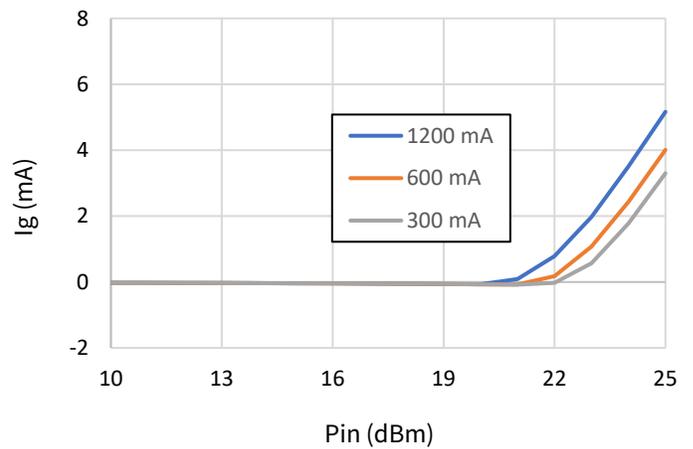
**Figure 34: PAE v. Pin v. Idq**



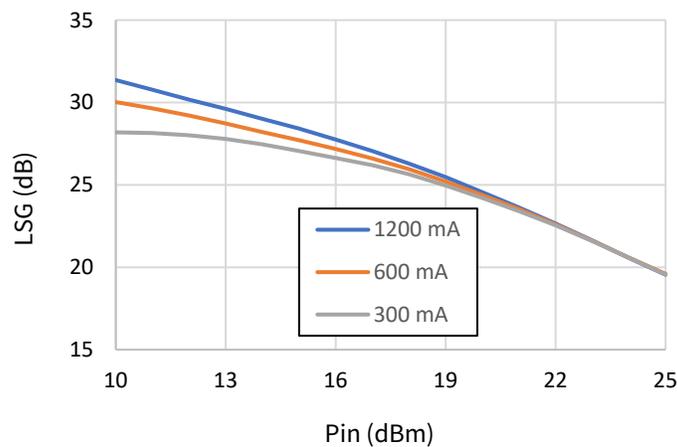
**Figure 35: Id v. Pin v. Idq**



**Figure 36: Ig v. Pin v. Idq**

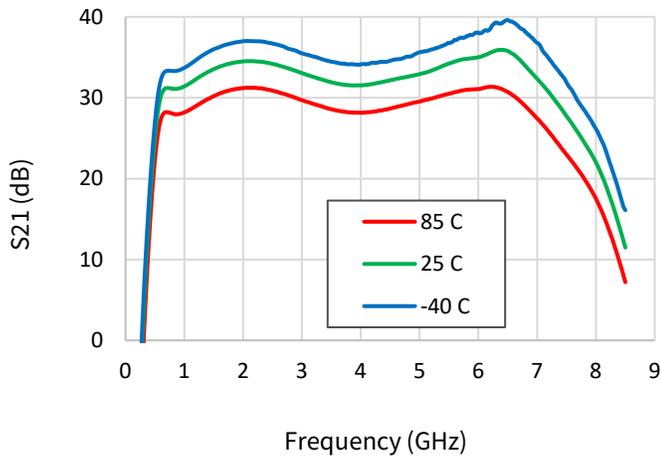


**Figure 37: Gain v. Pin v. Idq**

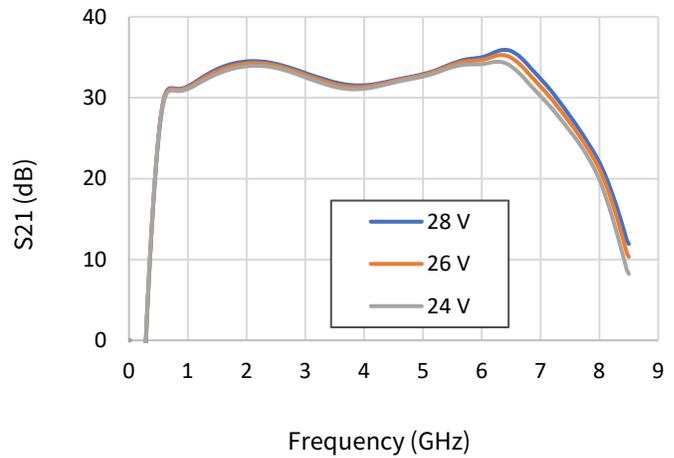


Test conditions unless otherwise noted: Vd=28 V, Idq=600mA, CW, Pin = 23 dBm, T<sub>base</sub>=25 °C

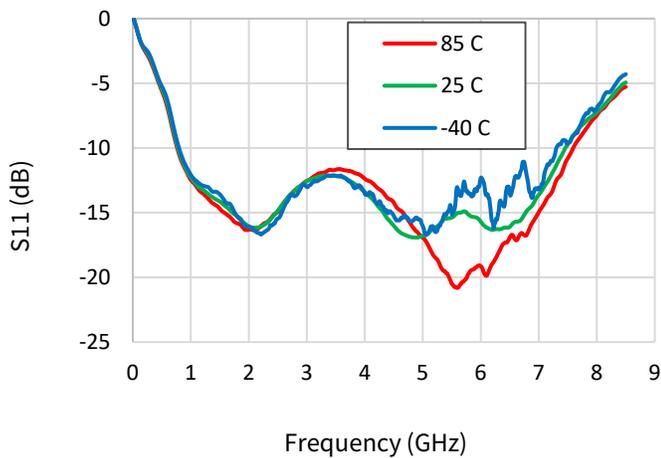
**Figure 38: S21 v. Frequency v. Temperature**



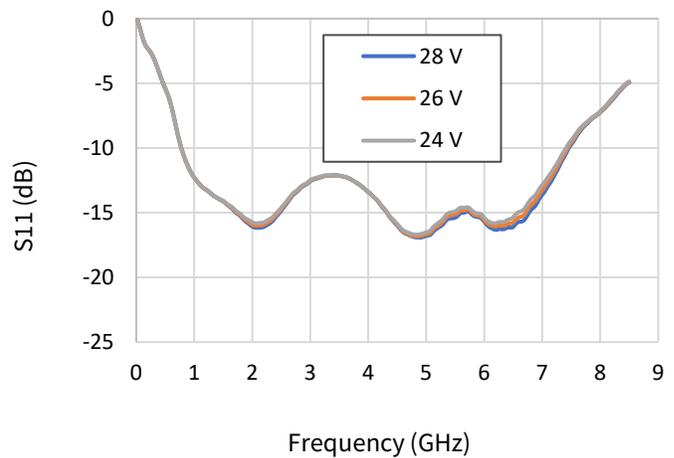
**Figure 39: S21 v. Frequency v. Vd**



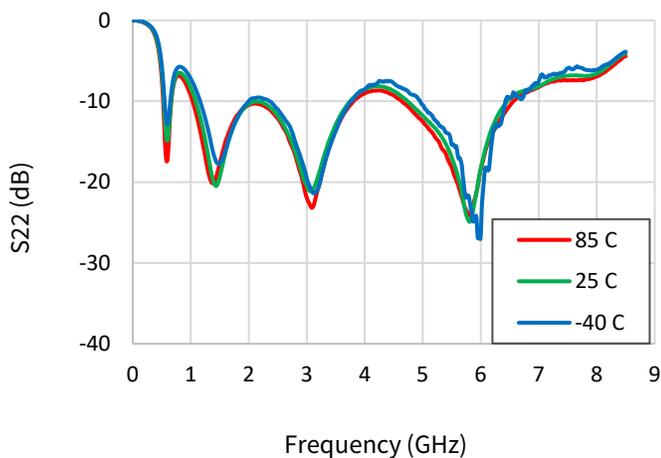
**Figure 40: S11 v. Frequency v. Temperature**



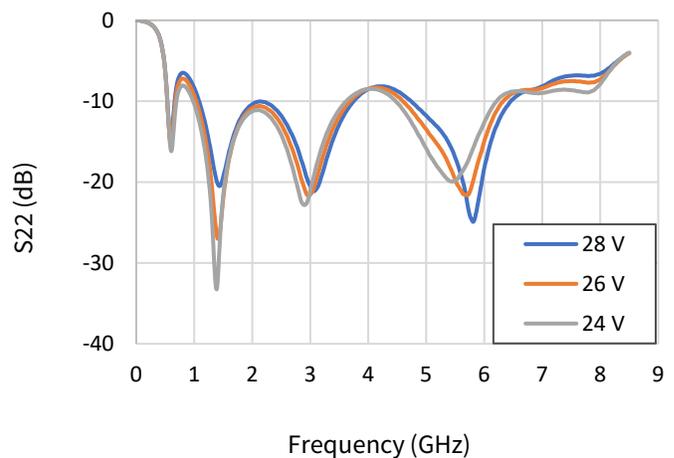
**Figure 41: S11 v. Frequency v. Vd**



**Figure 42: S22 v. Frequency v. Temperature**

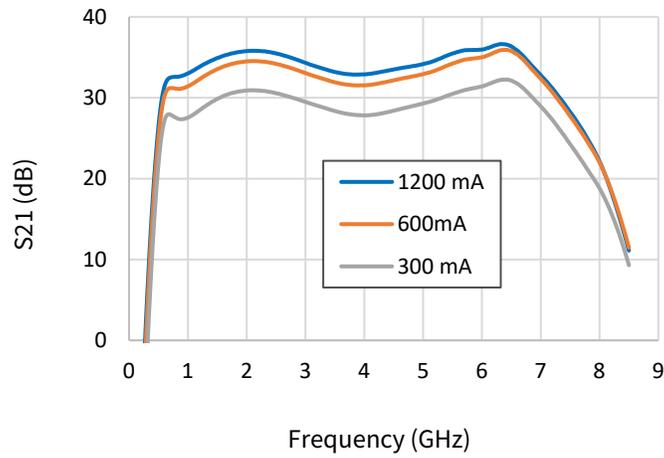


**Figure 43: S22 v. Frequency v. Vd**

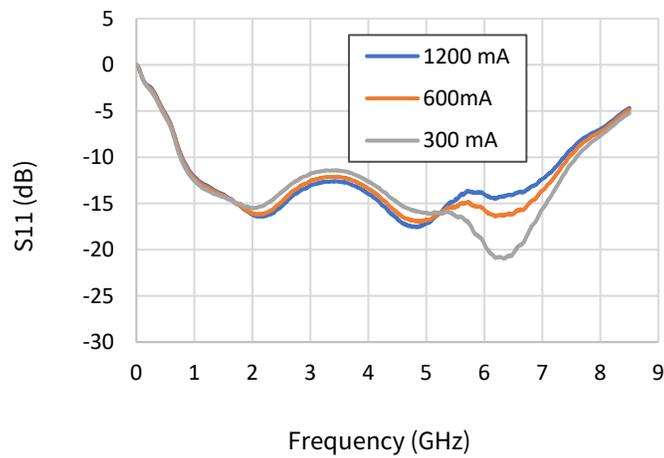


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=600\text{ mA}$ , CW,  $P_{in} = 23\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$

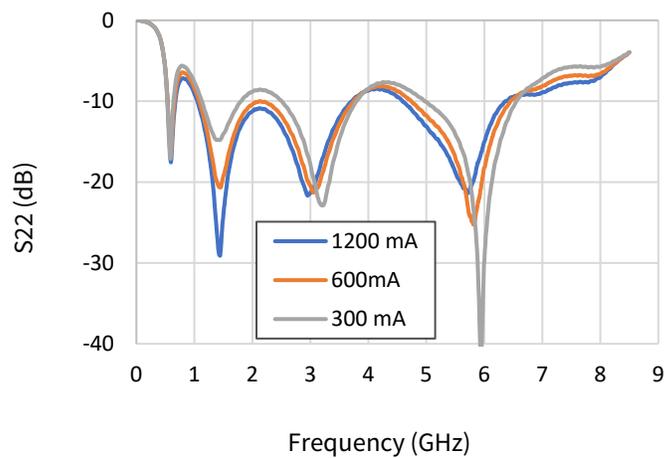
**Figure 44: S21 v. Frequency v. Idq**



**Figure 45: S11 v. Frequency v. Idq**



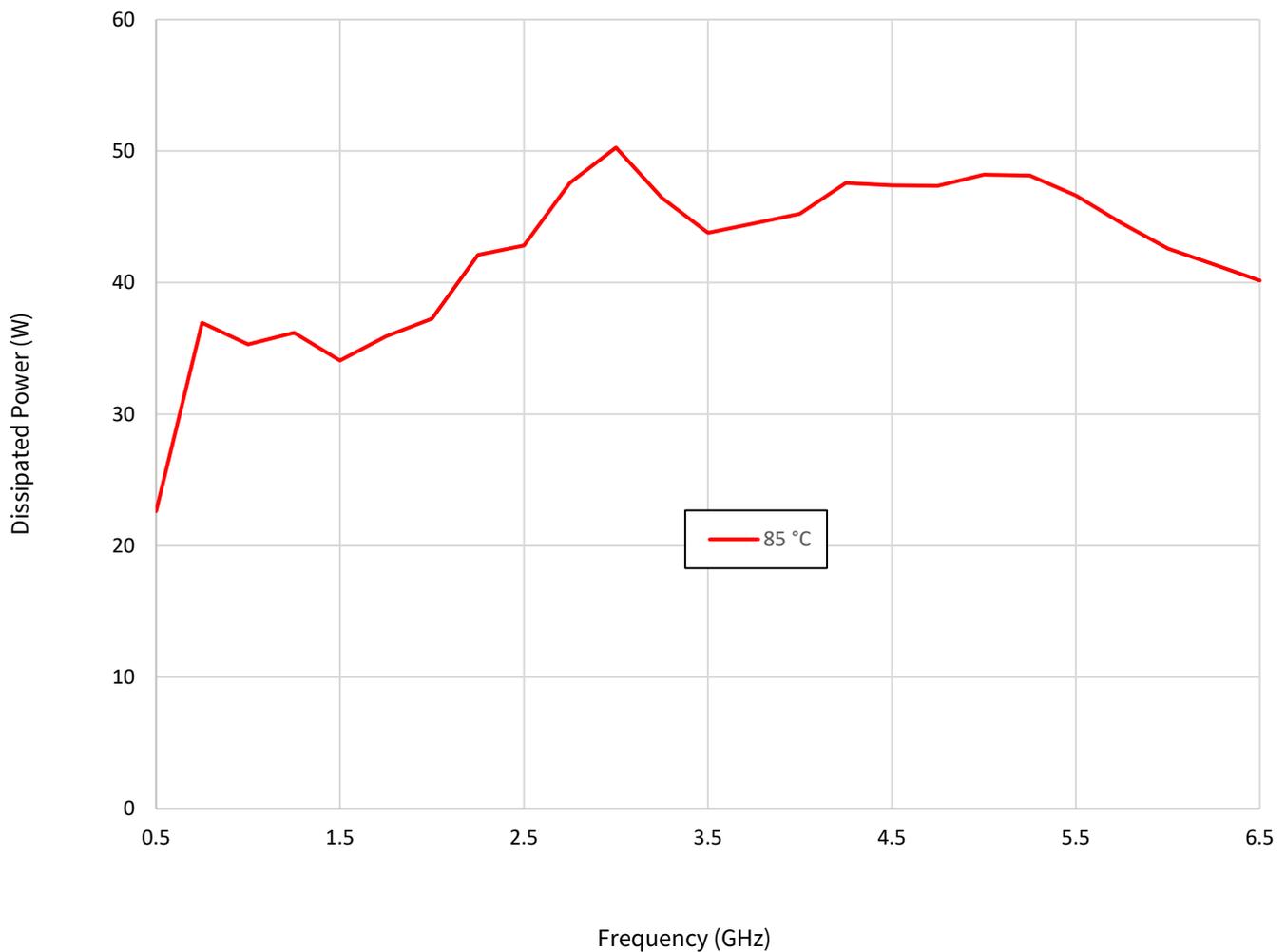
**Figure 46: S22 v. Frequency v. Idq**



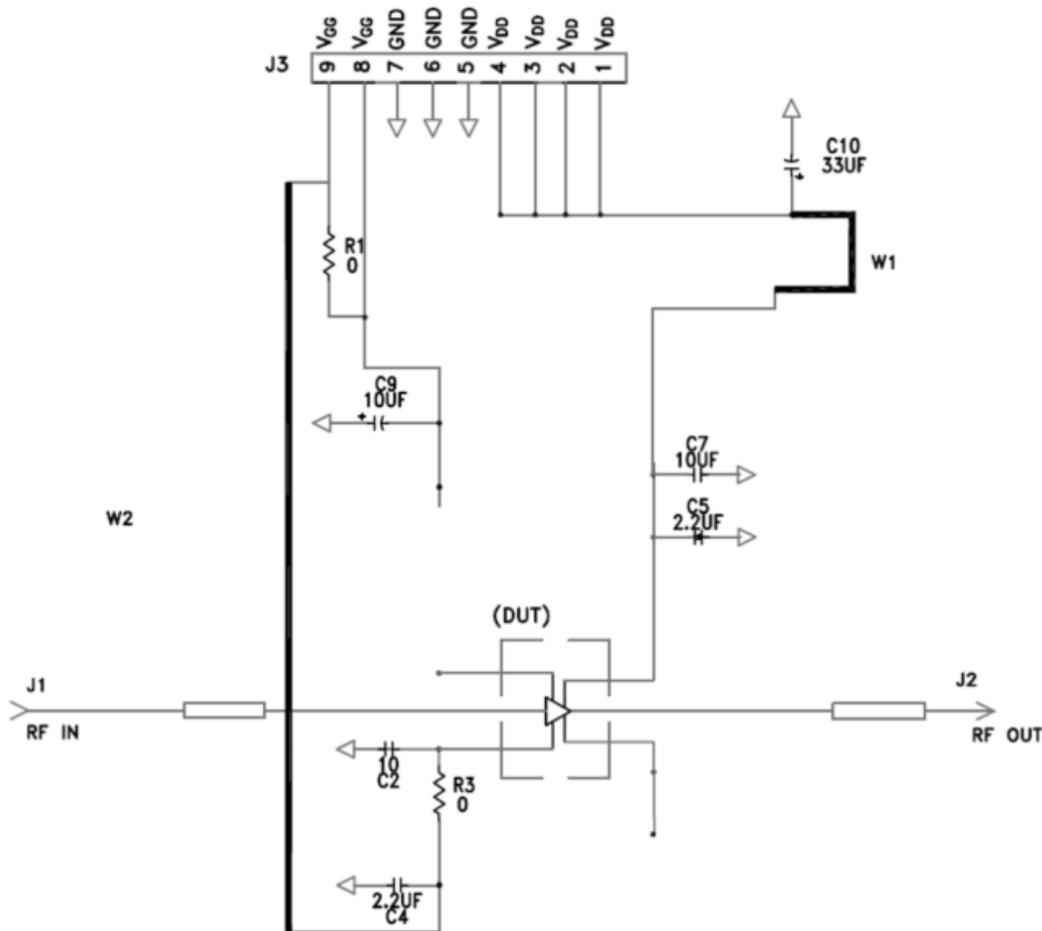
**Thermal Characteristics**

Parameter	Symbol	Value	Operating Conditions
Operating Junction Temperature	$T_J$	150	Freq = 3.0 GHz, $V_d = 28$ V, $I_{dq} = 600$ mA, $I_{drive} = 2.8$ A , $P_{in} = 23$ dBm, $P_{out} = 44.6$ dBm, $P_{diss} = 50$ W, $T_{case} = 85^\circ\text{C}$ , PW=CW
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.3	

**Power Dissipation v. Frequency ( $T_{case} = 85^\circ\text{C}$ )**



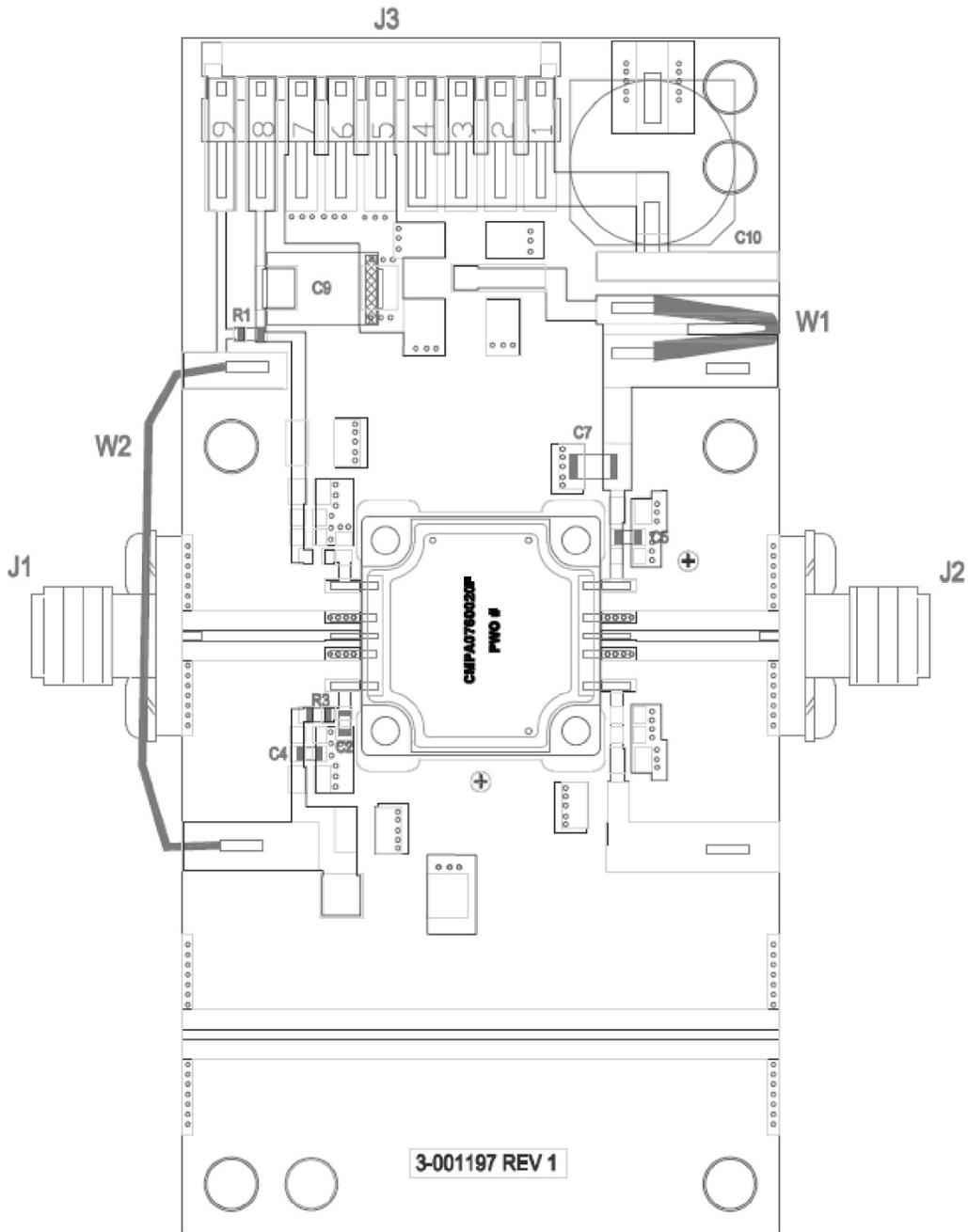
**CMPA0760020F-AMP Evaluation Board Schematic Drawing**



**CMPA0760020F-AMP Evaluation Board Bill of Materials**

Reference Designator	Description	Qty
R1, R3	RESISTOR 0 ohm, 0603	2
C2	CAP, 10pF, +/- 5%, 0603, ATC	1
C4, C5	CAP, 2.2uf, 50v, 0603	2
C10	CAP, 33 UF, 20%, G CASE	1
C7	CAP, 10uf, 50v, 1206	1
C9	CAP 10UF 16V TANTALUM, 2312	1
-	PCB, RO3003, 3.0 x 1.5 x 0.01 ", CMPA0760020F	1
-	BASEPLATE 3.0 x 1.5 x 0.25 IN	1
-	2-56 SOC HD SCREW 3/16 SS	4
-	#2 SPLIT LOCKWASHER SS	4
J1, J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20MIL	2
J3	HEADER RT>PLZ .1CEN LK 9POS	1
W1-2	WIRE, BLACK, 22 AWG	2
U1 (DUT)	CMPA0760020F	1

**CMPA0760020F-AMP Evaluation Board Assembly Drawing**



**Bias On Sequence**

1. Ensure RF is turned-off
2. Apply pinch-off voltage of -5 V to the gate ( $V_g$ )
3. Apply nominal drain voltage ( $V_d$ )
4. Adjust  $V_g$  to obtain desired quiescent drain current ( $I_{dq}$ )
5. Apply RF

**Bias Off Sequence**

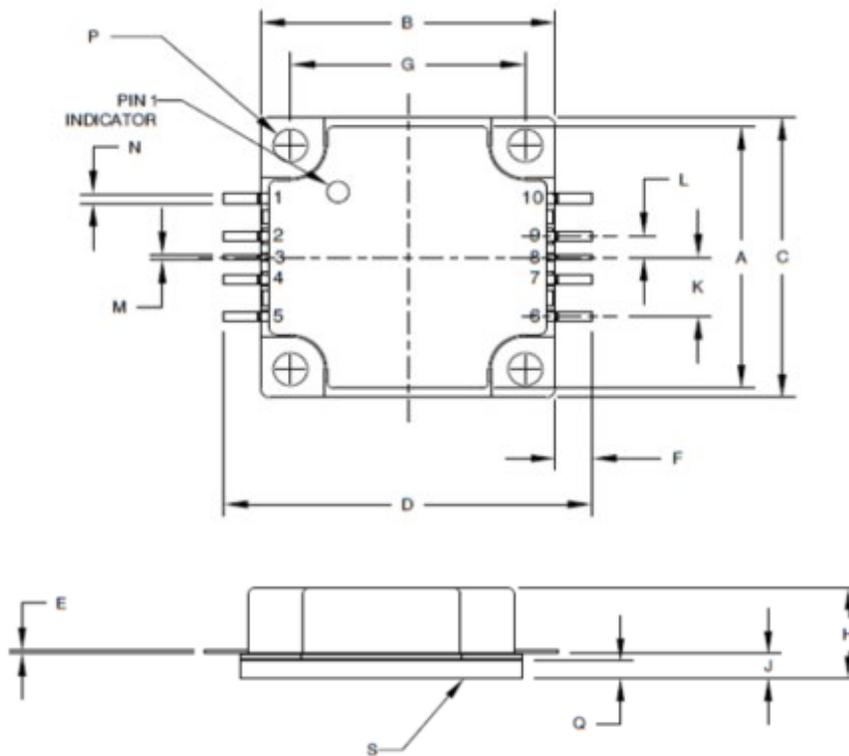
1. Turn RF off
2. Apply pinch-off to the gate ( $V_g=-5V$ )
3. Turn off drain voltage ( $V_d$ )
4. Turn off gate voltage ( $V_g$ )

**Product Dimensions**

DIM	INCHES			MILLIMETERS		
	MIN	TYP	MAX	MIN	TYP	MAX
A	.555	.560	.565	14.10	14.22	14.35
B	.595	.600	.605	15.11	15.24	15.37
C	.595	.600	.605	15.11	15.24	15.37
D	-	(.750)	-	-	(19.05)	-
E	.006	.008	.010	0.15	0.20	0.25
F	.065	.075	.085	1.66	1.91	2.16
G	.473	.478	.483	12.01	12.14	12.27
H	.191	.203	.215	4.86	5.16	5.46
J	.049	.056	.063	1.24	1.42	1.60
K	.121	.126	.131	3.07	3.20	3.33
L	.041	.046	.051	1.04	1.17	1.30
M	.005	.010	.015	0.13	.25	0.38
N	.015	.020	.025	0.38	.51	0.63
P	.065	.070	.075	1.65	1.78	1.90
Q	.038	.040	.042	0.97	1.02	1.07

NOTES: UNLESS OTHERWISE SPECIFIED

1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
2. PINS:  
1-10 DEFINED BY PRODUCT
3. THE CONTENTS OF THIS DRAWING ARE INTENDED TO REPRESENT THE PRODUCT IN MARKETING GRAPHICS ONLY AND NOT INTENDED TO BE USED FOR ANY PRODUCTION OR INTERNAL QUALIFICATION PURPOSE.



PIN	DESC.	PIN	DESC.
1	NC	6	NC
2	RFGND	7	RFGND
3	RF input	8	RF output
4	RFGND	9	RFGND
5	Gate	10	Drain

## Electrostatic Discharge (ESD) Classification

Parameter	Symbol	Class	Classification Level	Test Methodology
Human body Model	HBM	TBD	ANSI/ESDA/JEDEC JS-001 Table 3	JEDEC JESD22 A114-D
Charge Device Model	CDM	TBD	ANSI/ESDA/JEDEC JS-002 Table 3	JEDEC JESD22 C101-C

## Product Ordering Information

Part Number	Description	MOQ Increment	Image
CMPA0760020F	0.7 – 6 GHz, 25W GaN MMIC		
CMPA0760020F-AMP	Evaluation Board w/ PA	1 Each	

## Notes & Disclaimer

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